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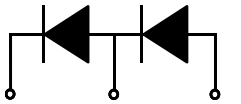
FFPF60B150DS

Features

- High voltage and high reliability
- High speed switching
  Modulation diode / Damper diode
- Low conduction loss
  Modulation diode / Damper diode



TO-220F



Damper Modulation

Applications

- (Modulation + Damper) diode designed for horizontal deflection circuits in C-TVs & monitors

DAMPER + MODULATION DIODE

Absolute Maximum Ratings (Modulation) T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ T_C = 100°C	20	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	120	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C

Absolute Maximum Ratings (Damper) T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	1500	V
$I_{F(AV)}$	Average Rectified Forward Current @ T_C = 100°C	6	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C

Thermal Characteristics

Symbol	Parameter	Value	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.3	°C/W

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Electrical Characteristics*(Modulation) T_C=25 ºC unless otherwise noted

Symbol	Parameter		Min.	Typ.	Max.	Units
V_{FM}	Maximum Instantaneous Forward Voltage					V
	I_F = 20A	T_C = 25 °C			2.2	
	I_F = 20A	T_C = 100 °C			2.0	
I_{RM}	Maximum Instantaneous Reverse Current					µA
	@ rated V_R	T_C = 25 °C			10	
		T_C = 100 °C			100	
t_{rr}	Maximum Reverse Recovery Time				90	ns
I_{rr}	Maximum Reverse Recovery Current				8	A
Q_{rr}	Maximum Reverse Recovery Charge				360	nC
	(I_F =20A, di/dt = 200A/µs)					

* Pulse Test: Pulse Width=300µs, Duty Cycle=2%

Electrical Characteristics*(Damper) T_C=25 ºC unless otherwise noted

Symbol	Parameter		Min	Typ	Max	Units
V_{FM}	Maximum Instantaneous Forward Voltage					V
	I_F = 6A	T_C = 25 °C			1.6	
	I_F = 6A	T_C = 100 °C			1.4	
I_{RM}	Maximum Instantaneous Reverse Current					µA
	@ rated V_R	T_C = 25 °C			7	
		T_C = 100 °C			60	
t_{rr}	Maximum Reverse Recovery Time				170	ns
	(I_F =1.0A, di/dt = 50A/µs)					
t_{fr}	Maximum Forward Recovery Time				350	ns
	(I_F =6.5A, di/dt = 50A/µs)					
V_{FRM}	Maximum Forward Recovery Voltage				17	V

* Pulse Test: Pulse Width=300µs, Duty Cycle=2%

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Typical Characteristics

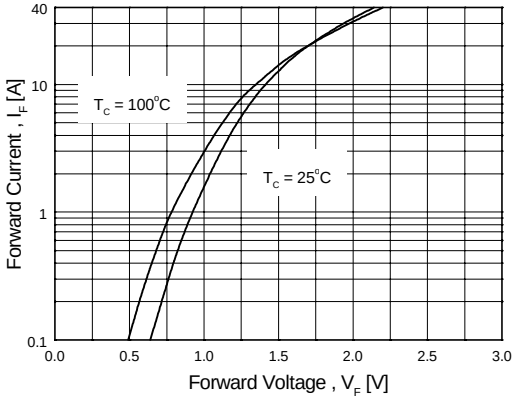


Figure 1. Typical Forward Characteristics (Modulation Diode)

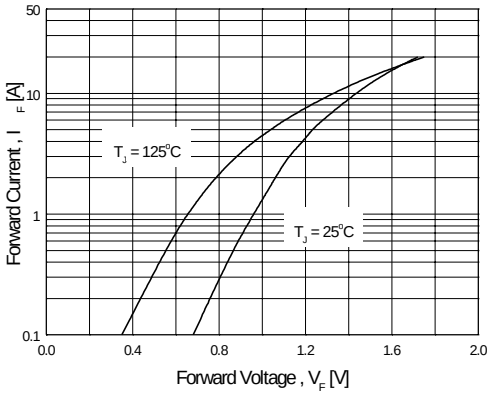


Figure 2. Typical Forward Characteristics (Damper Diode)

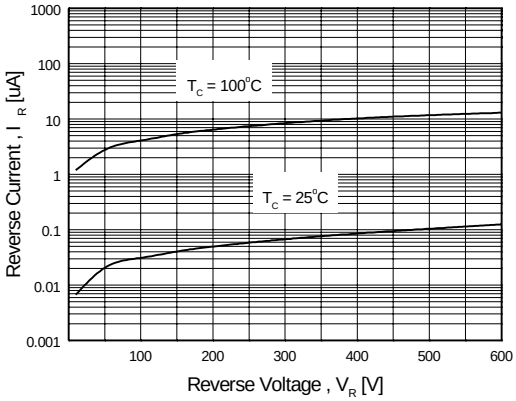


Figure 3. Typical Reverse Current vs. Reverse Voltage (Modulation Diode)

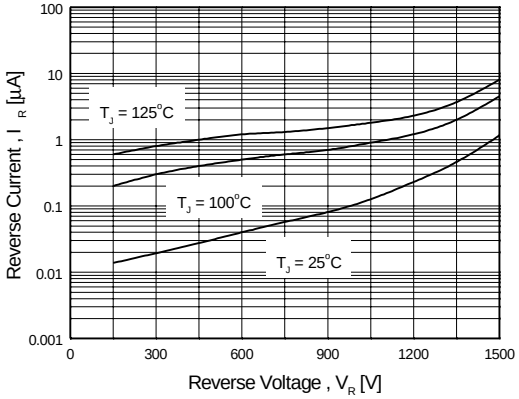


Figure 4. Typical Reverse Current vs. Reverse Voltage (Damper Diode)

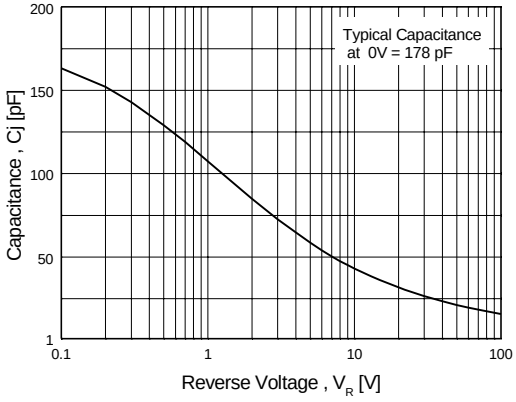


Figure 5. Typical Junction Capacitance (Modulation Diode)

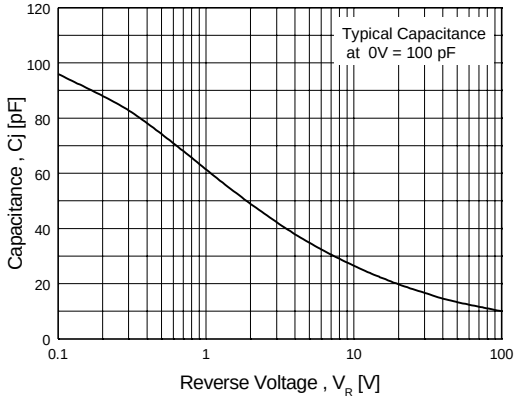


Figure 6. Typical Junction Capacitance (Damper Diode)

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Typical Characteristics

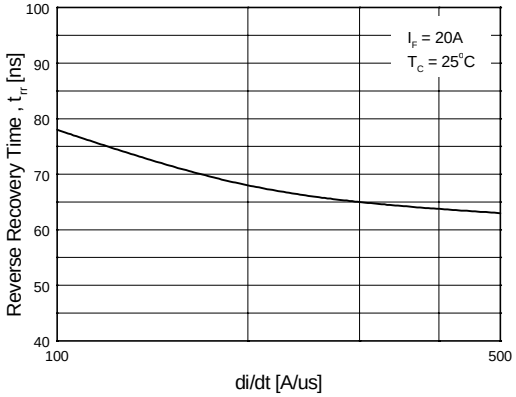


Figure 7. Typical Reverse Recovery Time vs. di/dt (Modulation Diode)

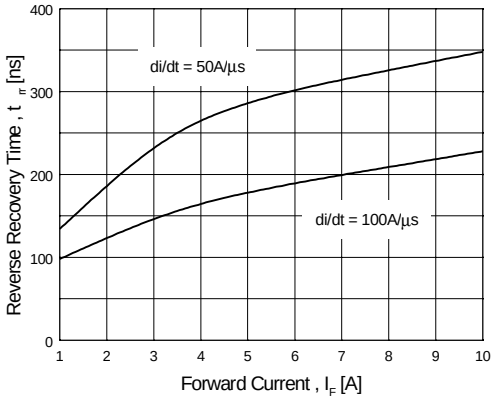


Figure 8. Typical Reverse Recovery Time vs. di/dt (Damper Diode)

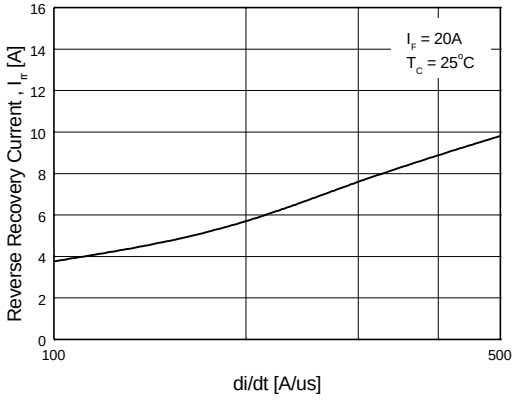


Figure 9. Typical Reverse Recovery Current vs. di/dt (Modulation Diode)

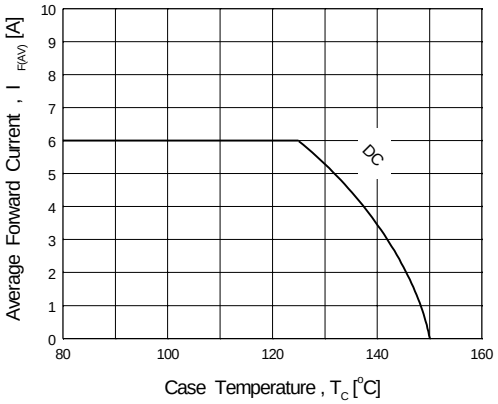


Figure 10. Forward Current Derating Curve (Damper Diode)

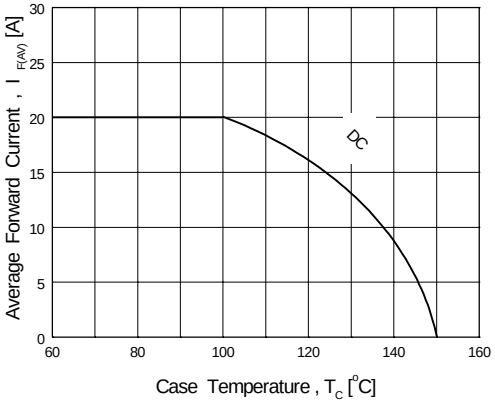
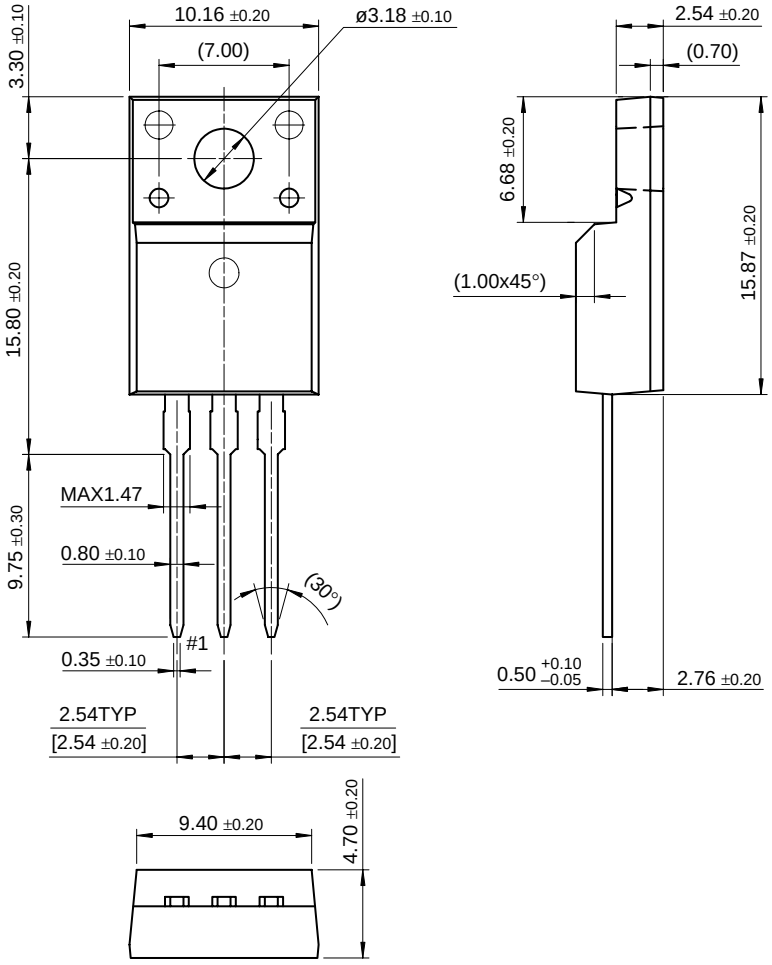


Figure 11. Forward Current Derating Curve (Modulation Diode)

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Package Dimensions

TO-220F



Dimensions in Millimeters

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FFPF60B150DS
6A/1500V Damper and 20A/600V Modulation Diode

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Design tools

Features

- High voltage and high reliability
- High speed switching Modulation diode / Damper diode
- Low conduction loss Modulation diode / Damper diode

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Applications

- (Modulation + Damper) diode designed for horizontal deflection circuits in C-TVs & monitors

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
FFPF60B150DSTU	Full Production	$0.89	TO-220F	3	RAIL

* 1,000 piece Budgetary Pricing

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